

View Online at <https://aerobasegroup.com/nsn/5961-00-401-6652>

Inclosure Material:

Metal

Overall Length:

Between 0.140 inches and 0.260 inches

Terminal Length:

1.500 inches

Overall Diameter:

Between 0.335 inches and 0.370 inches

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Features Provided:

Burn in

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open all transistor and 7.0 emitter to base voltage, static, collector open all transistor and 30.0 collector-to-emitter, sustaining voltage, base open-circuited all transistor

Power Rating Per Characteristic:

200.0 milliwatts small-signal input power, common-collector absolute all transistor

Maximum Operating Temperature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

All transistor junction pattern arrangement: npn

Terminal Type And Quantity:

6 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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